NSN 5961-01-169-4086

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-169-4086 **Inclosure Material:** Metal and glass **Overall Length:** 2.637 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-83 **Mounting Method:** Threaded stud **Features Provided:** Mounting hardware **Overall Width Across Flats:** 1.050 inches **Thread Size:** 0.469 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 repetitive peak off-state voltage and 3.0 gate trigger voltage, instantaneous **Current Rating Per Characteristic:** 110.00 amperes forward current, total rms pascal and 75.00 milliamperes forward current, total rms absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 threaded stud and 1 unthreaded hole and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: